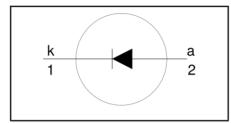
BY329 series

FEATURES

- Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- · Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 800 \text{ V} / 1000 \text{ V} / 1200 \text{ V}$$
 $I_{F(AV)} = 8 \text{ A}$
 $I_{FSM} \le 75 \text{ A}$
 $t_{rr} \le 135 \text{ ns}$

GENERAL DESCRIPTION

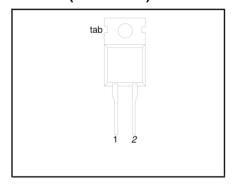
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY329 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V_{RSM}	Peak non-repetitive reverse	BY329	-	-800 800	-1000 1000	-1200 1200	V
$oldsymbol{V}_{RRM} \ oldsymbol{V}_{RWM}$	voltage Peak repetitive reverse voltage Crest working reverse voltage		-	800 600	1000 800	1200 1000	V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \leq 122 ^{\circ}\text{C}$	-		8		A
		sinusoidal; a = 1.57; T _{mb} ≤125 °C	-		/		Α
I _{F(RMS)}	RMS forward current		-		11		Α
I _{FRM}	Repetitive peak forward current	t = 25 μs; δ = 0.5; T _{mb} ≤122 °C	-		16		A
I _{FSM}	Non-repetitive peak forward	t = 10 ms	-		75		Α
1 0	current.	t = 8.3 ms	-		82		Α
		sinusoidal; T _i = 150 °C prior					
		to surge; with reapplied					
		V _{RWM(max)}					
l ² t	I ² t for fusing	t = 10 ms	-		28		A ² s
T _{stg}	Storage temperature		-40		150		°C
T_{j}	Operating junction temperature		-		150		°C

¹ Neglecting switching and reverse current losses.

BY329 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.0	K/W
R _{th j-a}		in free air.	-	60	-	K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

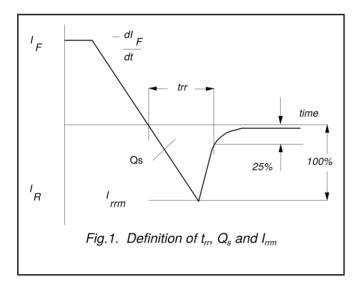
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage Reverse current	$I_F = 20 \text{ A}$ $V_R = V_{RWM}$; $T_j = 125 \text{ °C}$	1 1	1.5 0.1	1.85 1.0	V mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t,, Q,s dl _R /dt	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$		100 0.5 50	135 0.7 60	ns µC A/µs

BY329 series



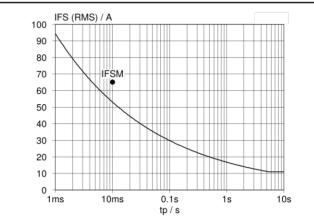


Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^{\circ}C$ prior to surge with reapplied V_{RWM} .

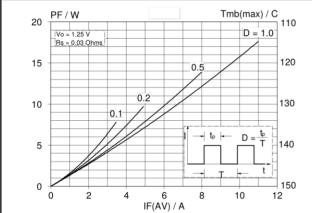


Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; square wave current waveform; parameter D = duty cycle = t_p/T .

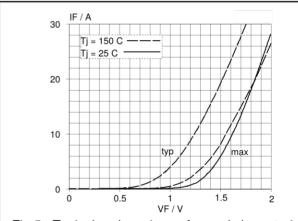


Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

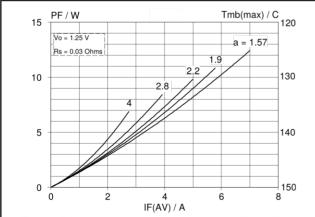
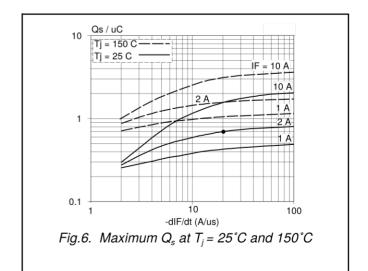
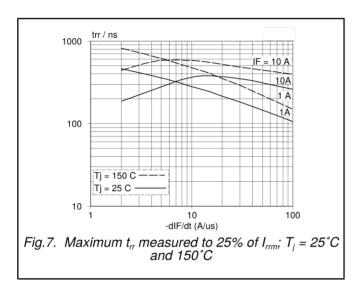
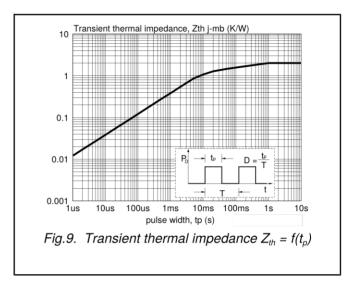


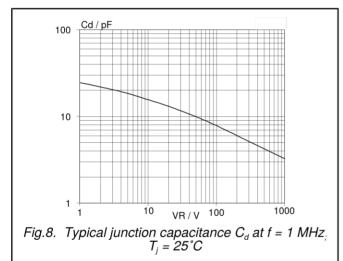
Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; sinusoidal current waveform; parameter a = form factor = $I_{F(BMS)}/I_{F(AV)}$.



BY329 series

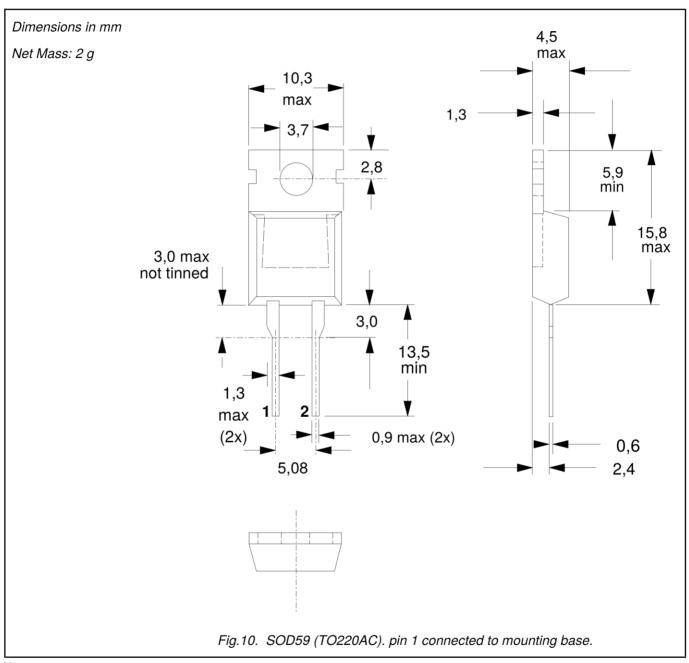






BY329 series

MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes fast, soft-recovery

BY329 series

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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